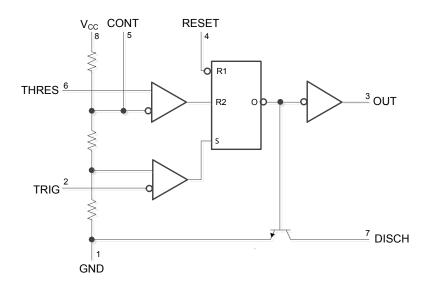


Pin Descriptions

Pin Name	Pin Number	Description
GND	1	Ground
TRIG	2	Trigger set 1/3V _{CC}
OUT	3	Timer output
RESET	4	Reset active low
CONT	5	External adjustment of internal threshold and trigger voltages
THRES	6	Threshold set to 2/3 V _{CC}
DISCH	7	Low impedance discharge path
Vcc	8	Chip supply voltage

Functional Block Diagram



RESET can override TRIG, which can override THRESH

Functional Table

RESET	Nominal Trigger Voltage	Threshold Voltage	Output	Discharge Switch
Low	Irrelevant	Irrelevant	Low	On
High	<1/3V _{CC}	Irrelevant	High	Off
High	>1/3V _{CC}	>2/3V _{CC}	Low	On
High	>1/3V _{CC}	<2/3V _{CC}	As previo	ously established



Absolute Maximum Ratings (Note 4) @ TA = 25°C unless otherwise stated

Symbol	Parameter		Rating	Unit
Vcc	Supply voltage (Note 5)		18	V
VI	Input voltage	CONT, RESET, THRES, TRIG	V _{CC}	V
lo	Output current	Output current		mA
θ_{JA}	Package thermal resistance Junction-to-Ambient (Note 6)		130	°C/W
θЈС	Package thermal resistance Junction-to-Case (Note 7)		15	°C/W
TJ	Junction temperature		150	°C
T _{STG}	Storage temperature		-65 to 150	°C

Notes:

- 4. Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 5. All voltage values are with respect ground.
- 6. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is
- c. Incamount power dissipation is a function of $I_J(max)$, σ_{JA} , and I_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

 7. Maximum power dissipation is a function of $T_J(max)$, θ_{JC} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_C)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

Recommended Operating Conditions (TA = 25°C)

Symbol	Pa	Min	Max	Unit	
V_{CC}	Supply voltage		4.5	16	V
Vı	Input voltage	CONT, RESET, THRES, TRIG	_	Vcc	V
Io	Output current		_	±200	mA
		NE555	0	70	
TA	T _A Operating Ambient Temperature	SA555	-40	85	°C
		NA555	-40	105	

Electrical Characteristics (V_{CC} = 5V to 15V, T_A = 25°C unless otherwise stated)

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
	Threehold welfage level	V _{CC} = 15V	8.8	10	11.2	.,,
V_{TH}	Threshold voltage level	V _{CC} = 5V	2.4	3.3	4.2	V
I_{TH}	Threshold current (Note 8)	_	_	30	250	nA
\/	Trianguistana laval	V _{CC} = 15V	4.5	5	5.6	V
V_{TR}	Trigger voltage level	V _{CC} = 5V	1.1	1.67	2.2	V
I_{TR}	Trigger current	TRIG at 0V	_	0.5	2	μΑ
V _{RST}	RESET voltage level	_	0.3	0.7	1	V
1	DECET assert	RESET at V _{CC}	_	0.1	0.4	^
I _{RST}	RESET current	RESET at 0V	_	-0.4	-1.5	mA
I _{DIS}	DISCH switch off-state current	_	_	20	100	nA
\ /	DISCH saturation voltage with output	V _{CC} = 15V, I _{DIS} = 15mA	_	180	480	.,,
V_{DIS}		V _{CC} = 5V, I _{DIS} = 4.5mA	_	80	200	mV
\/	CONT. valtage (annu sinovit)	V _{CC} = 15V	9	10	11	.,
V_{CON}	CONT voltage (open circuit)	V _{CC} = 5V	2.6	3.3	4	V

Notes:

^{8.} This parameter influences the maximum value of the timing resistors R_A and R_B in the circuit of Figure 12. For example, when V_{CC} = 5 V, the maximum value is R = R_A + R_B \approx 3.4M Ω , and for V_{CC} = 15 V, the maximum value is 10M Ω .

^{9.} No protection against excessive pin 7 current is necessary providing package dissipation rating is not exceeded



Electrical Characteristics (V_{CC} = 5V to 15V, T_A = 25°C unless otherwise stated)

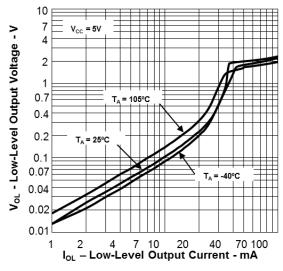
Symbol	Parameter	Test conditi	ons	Min	Тур.	Max	Unit
		V _{CC} = 15V, I _{OL} = 10mA		_	0.1	0.25	
		V _{CC} = 15V, I _{OL} = 50mA	V _{CC} = 15V, I _{OL} = 50mA		0.4	0.75	
\ <u>'</u>	Law lawal autout valtage	V _{CC} = 15V, I _{OL} = 100mA		1	2	2.5	
V _{OL}	Low level output voltage	V _{CC} = 15V, I _{OL} = 200mA		1	2.5	_	V
		V_{CC} = 5V, I_{OL} = 5mA		1	0.1	0.35	
		V_{CC} = 5V, I_{OL} = 8mA		1	0.15	0.4	
		$V_{CC} = 15V, I_{OH} = -100mA$		12.75	13.3	_	
V _{OH}	High level output voltage	$V_{CC} = 15V, I_{OH} = -200mA$		1	12.5	_	V
		$V_{CC} = 5V$, $I_{OH} = -100$ mA		2.75	3.3	_	
		Outmut law male ad	V _{CC} = 15V	1	10	15	
	Supply current	Output low, no load	$V_{CC} = 5V$	1	3	6	
Icc		Output high, no load	V _{CC} = 15V	1	9	13	mA -
			$V_{CC} = 5V$	1	2	5	
	Initial error of timing interval (Note 10)	Each time, monostable			4	2	- %
T _{ER}		(Note 11)			1	3	
TER		Each time, astable		_	2.25	_	
		(Note 12)			2.25		
		Each time, monostable		_	50	_	ppm/°C
T _{TC}	Temperature coefficient of timing	(Note 11)	T _A = full range				
.10	interval	Each time, astable	i A i a ii i a ii go	_ 1	150	_	
		(Note 12)					
	Supply voltage sensitivity of timing interval	Each time, monostable		_	0.1	0.5	- %/∨
T _{VCC}		(Note 11)					
		Each time, astable		_	0.3	_	
		(Note 12)					
T _{RI}	Output pulse rise time		C _L = 15pF	_		300	ns
T _{FA}	Output pulse fall time		$C_L = 15pF$	_	_	300	ns

Notes:

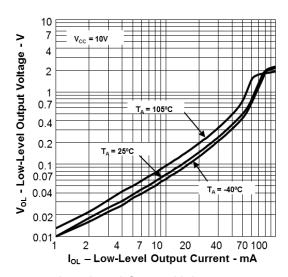
^{10.} Timing interval error is defined as the difference between the measured value and the average value of a random sample from each process run. 11. Values specified are for a device in a monostable circuit similar to Figure 9, with the following component values: $R_A = 2k\Omega$ to $100k\Omega$, C = 0.1uF. 12. Values specified are for a device in an astable circuit similar to Figure 12, with the following component values: $R_A = 1k\Omega$ to $100k\Omega$, C = 0.1uF.



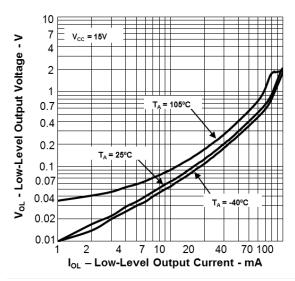
Typical Performance Characteristics



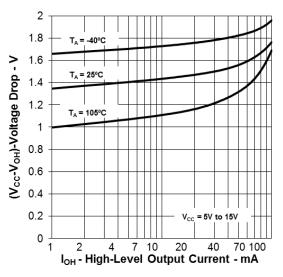
Low Level Output Voltage vs. Low Level Output Current @ $V_{CC} = 5V$



Low Level Output Voltage vs. Low Level Output Current @ $V_{CC} = 10V$



Low Level Output Voltage vs. Low Level Output Current @ V_{CC} = 15V



Drop Between Supply Voltage and Output vs.
High Level Output Current



1.015

1.01

1.005

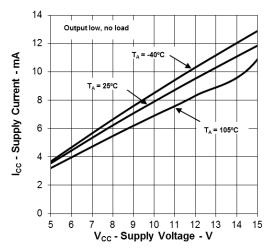
0.995

0.99

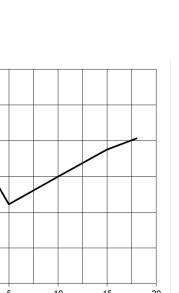
0.985 -

Pulse Duration Relative to Value @ $V_{\rm CC}$ = 10V

Typical Performance Characteristics (cont.)

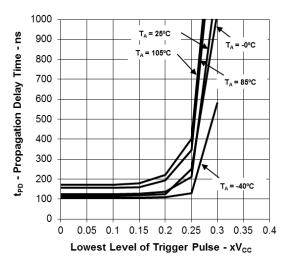


Supply Current vs. Supply Voltage

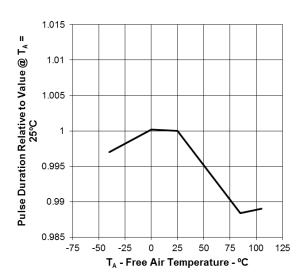


Normalized Output Pulse Duration (Monostable Mode) vs. Supply Voltage

V_{cc} - Supply Voltage - V



Propagation Delay Time vs. Lowest Voltage Level of Trigger Pulse



Normalized Output Pulse Duration (Monostable Mode) vs. Free-Air Temperature



Typical Applications Characteristics

Monostable Operation

For monostable operation, any of the '555 timers can be connected as shown in Figure 1. If the output is low, application of a negative-going pulse to the trigger (TRIG) sets the internal flip-flop and drives the output high. Capacitor C is then charged through R_A until the voltage across the capacitor reaches the threshold voltage of the threshold (THRES) input. If TRIG has returned to a high level, the output of the threshold comparator resets the internal flip-flop, drives the output low, and discharges C.

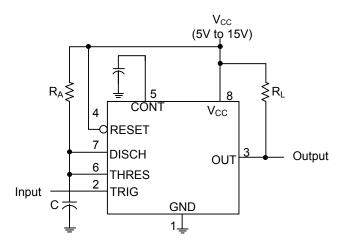


Fig. 1 Monostable operation

Monostable operation is initiated when TRIG voltage falls below the trigger threshold. Once initiated, the sequence ends only if TRIG is high for at least 10 μ s before the end of the timing interval. When the trigger is grounded, the comparator storage time can be as long as 10 μ s, which limits the minimum monostable pulse width to 10 μ s. Because of the threshold level and saturation voltage of Q1, the output pulse duration is approximately $t_W = 1.1R_AC$. Figure 3 is a plot of the time constant for various values of R_A and R_A . The threshold levels and charge rates both are directly proportional to the supply voltage, R_A . The timing interval is, therefore, independent of the supply voltage, so long as the supply voltage is constant during the time interval.

Applying a negative-going trigger pulse simultaneously to RESET and TRIG during the timing interval discharges C and reinitiates the cycle, commencing on the positive edge of the reset pulse. The output is held low as long as the reset pulse is low. To prevent false triggering, when RESET is not used, it should be connected to V_{CC}.

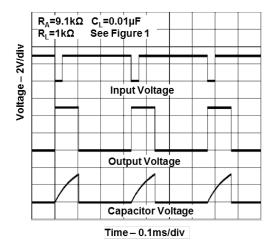


Fig. 2 Typical Monostable Waveforms

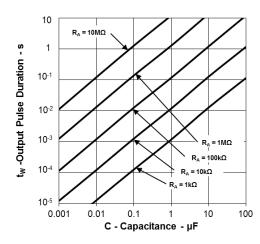


Fig. 3 Output Pulse Duration vs. Capacitance



Astable Operation

As shown in Figure 4, adding a second resistor, R_B , to the circuit of Figure 1 and connecting the trigger input to the threshold input causes the timer to self-trigger and run as a multivibrator. The capacitor C charges through R_A and R_B and then discharges through R_B . Therefore, the duty cycle is controlled by the values of R_A and R_B .

This astable connection results in capacitor C charging and discharging between the threshold-voltage level ($\approx 0.67 V_{CC}$) and the trigger-voltage level ($\approx 0.33 V_{CC}$). As in the monostable circuit, charge and discharge times (and, therefore, the frequency and duty cycle) are independent of the supply voltage.

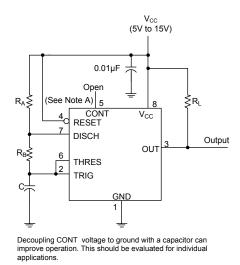


Fig. 4 Circuit for Astable Operation

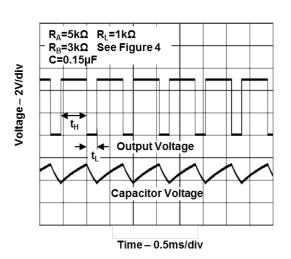


Fig. 5 Typical Astable Waveforms

Figure 5 shows typical waveforms generated during a table operation. The output high-level duration t_H and low-level duration t_L can be calculated as follows:

$$t_H = 0.693(R_A + R_B)C$$

 $t_L = 0.693(R_B)C$

Other useful equations are:

period =
$$t_H + t_L = 0.693(R_A + 2R_B)C$$

frequency = $1.44/(R_A + 2R_B)C$
output driver duty cycle = $t_L/(t_H + t_L) = R_B/(R_A + 2R_B)$
output waveform duty cycle = $t_H/(t_H + t_L) = 1 - R_B/(R_A + 2R_B)$
low to high ratio = $t_L/t_H = R_B/(R_A + R_B)$

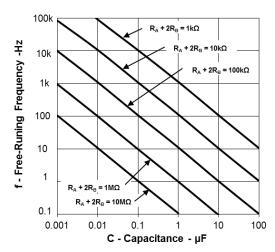
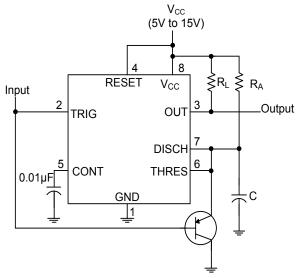


Fig. 6 Free Running Frequency



Missing Pulse Detector

The circuit shown in Figure 7 can be used to detect a missing pulse or abnormally long spacing between consecutive pulses in a train of pulses. The timing interval of the monostable circuit is retriggered continuously by the input pulse train as long as the pulse spacing is less than the timing interval. A longer pulse spacing, missing pulse, or terminated pulse train permits the timing interval to be completed, thereby generating an output pulse as shown in Figure 8.



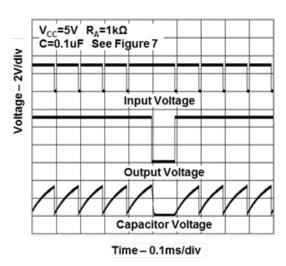
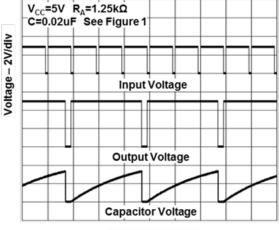


Fig. 7 Circuit for Missing Pulse Detector

Fig. 8 Timing Waveforms for Missing Pulse Detector

Frequency Divider

By adjusting the length of the timing cycle, the basic circuit of Figure 1 can be made to operate as a frequency divider. Figure 9 shows a divide-by-three circuit that makes use of the fact that retriggering cannot occur during the timing cycle.



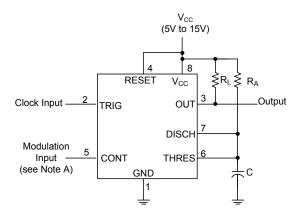
Time - 0.1ms/div

Fig. 9 Divide by Three Circuit Waveforms

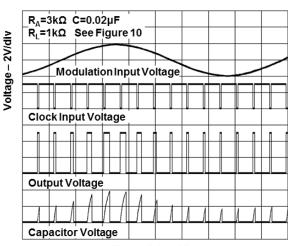


Pulse Width Modulation

The operation of the timer can be modified by modulating the internal threshold and trigger voltages, which is accomplished by applying an external voltage (or current) to CONT. Figure 10 shows a circuit for pulse-width modulation. A continuous input pulse train triggers the monostable circuit, and a control signal modulates the threshold voltage. Figure 11 shows the resulting output pulse-width modulation. While a sine-wave modulation signal is shown, any wave shape could be used.



The modulating signal can be directly or capacitively coupled to CONT. For direct coupling, the effects of modulation source voltage and impedance on the bias of the timer should be considered.



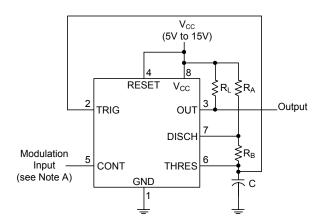
Time - 0.4ms/div

Fig. 10 Circuit for Pulse width modulation

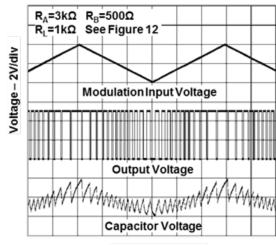
Fig. 11 Pulse width modulation timing diagrams

Pulse Position Modulation

As shown in Figure 12, any of these timers can be used as a pulse-position modulator. This application modulates the threshold voltage and, thereby, the time delay, of a free-running oscillator. Figure 13 shows a triangular-wave modulation signal for such a circuit; however, any wave shape could be used.



The modulating signal can be directly or capacitively coupled to CONT. For direct coupling, the effects of modulation source voltage and impedance on the bias of the timer should be considered.



Time - 0.1ms/div

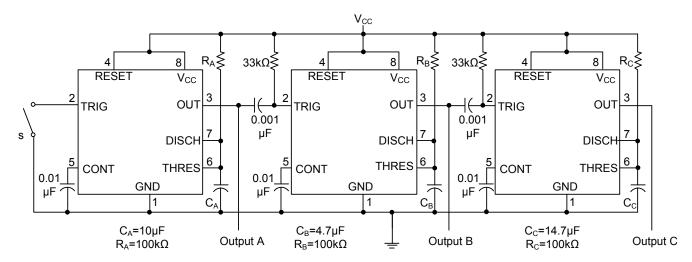
Fig. 12 Circuit for pulse position modulation

Fig. 13 Pulse position modulation timing diagrams



Sequential Timer

Many applications, such as computers, require signals for initializing conditions during start-up. Other applications, such as test equipment, require activation of test signals in sequence. These timing circuits can be connected to provide such sequential control. The timers can be used in various combinations of astable or monostable circuit connections, with or without modulation, for extremely flexible waveform control. Figure 14 shows a sequencer circuit with possible applications in many systems, and Figure 15 shows the output waveforms.



Note A: S closes momentarily at t=0.

Fig. 14 Circuit for Sequential Timer

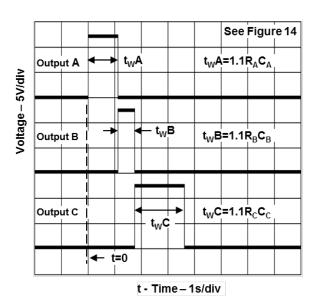
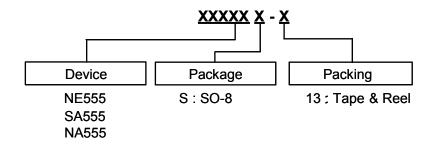


Fig. 15 Sequential timer waveforms



Ordering Information

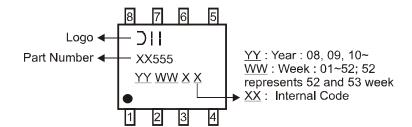


	Davies	Operating Posters Code		Packaging	13" Tape and Reel		
	Device	Temperature	Package Code	(Note 13)	Quantity	Part Number Suffix	
Pb Lead-free Green	NE555S-13	0 to 70°C	S	SO-8	2500/Tape & Reel	-13	
Pby Lead-free Green	SA555S-13	-40to 85°C	S	SO-8	2500/Tape & Reel	-13	
Pb Lead-free Green	NA555S-13	-40 to 105°C	S	SO-8	2500/Tape & Reel	-13	

Notes: 13. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SO-8

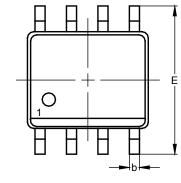


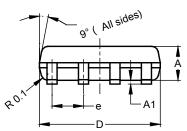


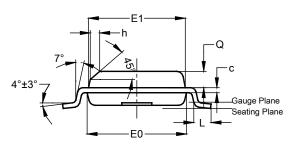
Package Outline Dimensions (All Dimensions in mm)

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8





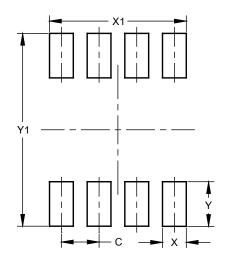


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A 1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h	-		0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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